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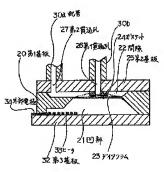
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#### Abstract of JP5240371

PURPOSE: To provide a micro-valve which is excellent in long-term stability and can drive plural valves at one time with a simple structure. CONSTITUTION: This micro-valve is provided with the first base board 20 where a recessed part 21 is formed in one surface and a diaphragm 23 is formed in the other surface of the recessed part 21, and at least one ringshaped gasket 24 which is fixed on the diaphragm 23. It is provided with the first through hole 26 which is arranged in an air tight condition at a prescribed interval 22 on the side where the diaphragm 23 of the first base board 20 is formed, and formed at a position facing the approximate center of the gasket 24, the second base board 25 which is formed at a position facing the outer periphery of the gasket 24 and provided with at least one second through hole 27, and the third base board 32 which covers the recessed part 21 and is arranged in an air tight condition. An expanding (or contracting) member is enclosed in the recessed part 21 by heating (or cooling) to provide a means for heating (or cooling) the member.



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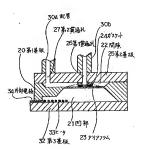
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## (54) 【発明の名称】 マイクロバルブ

## (57) 【要約】

[目的] 長期安定性にすぐれ、簡単な構成で複数のパ ルブを同時に駆動することが可能なマイクロパルブを提 供する。

「構成」 一方の雨に凹路が形成され、膝凹部と他方の面でガイアフラムが形成された第1番板と、前配ダイアフラム上に固定された少なくとも一つのリング状のガスケットと、前起第1基板のダイアフラムが形成された側に所定の間酸を右して気帳に配置され、前起ガスケットの外間に対向する位置に形成された第1買混乱及びガスケットの外間に対向する位置に形成された第1買混乱及びガスケットの外間に対向する位置に形成された第1回混乱をしたっつの第2貫調がで有する第2基板と、前起門部を型で気候に配置された第3基板とを有し、前距回部に加熱(若しくは冷却)により膨張(若しくは収納)する部材を封入するとともに、該部材の加熱(若しくは冷却)



【特許請求の範囲】

【請求項1】 一方の面に凹部が形成され、該凹部と他 方の面でダイアフラムが形成された第1基板と、前記ダ イアフラム上に固定された少なくとも一つのリング状の ガスケットと、前記第1基板のダイアフラムが形成され た側に所定の間隙を有して気密に配置され、前記ガスケ ットのほぼ中心に対向する位置に形成された第1貫通孔 B7パガスケットの外間に対向する位置に形成された少な くとも一つの第2貫通穴を有する第2基板と、前配凹部 を覆って気密に配置された第3基板とを有し、前配凹部 10 で、ダイアフラムを駆動する手段として気体の膨張によ に加熱 (若しくは冷却) により膨張 (若しくは収縮) す る部材を封入するとともに、該部材の加熱(若しくは冷 却) 手段を設けたことを特徴とするマイクロパルプ。

1

(発明の詳細な説明)

[0001]

「産業上の利用分野」本発明は、例えばシリコン基板上 に形成された超小型ガスクロマトグラフィのガス流路切 替えに用いて好適なマイクロバルブに関するものであ る.

[0002]

【従来の技術】従来、この種のマイクロパルプとしては 虫腺平1-154460に記載された図4に断面で示す 構造のものが知られている。図4において,1はシリコ ンからなる第1基板であり、このシリコン基板1にはエ ッチングにより形成された中央部にメサ部6を有するダ イアフラムが形成され、このダイアフラムを形成する凹 部に連通して溝7が形成されている。2はパイレックス ガラスからなる第2の基板で、メサ部6と溝7の位置に 合わせて流体の出入口となる貫通孔9,10が形成され ており、第1、第2の基板は陽極接合により重ねて形成 30 されている。

【0003】4は断面コ字状の支持部材であり、第1の 基板1に形成されたメサ部6の裏面を覆って接着剤によ り固定されている。5は圧電アクチュエータ(以下,単 にアクチュエータという)で、このアクチュエータ5は 一端が支持部材4の底部に、他端が第1基板のメサ部6 の事而に接して配置されている。12はアクチュエータ に毎日を印加するための重額である。

[0004] なお、第1の基板の厚さは0.3mm,第 2の基板の間隙Dは6μm程度であり、アクチュエータ 40 る。図において20はシリコン単結晶からなる第1基板 の断面は4.2mm<sup>2</sup>, 長さ9mm程度とされ150V の電圧により8 um程度変位する。

【0005】上記の構成のパルプによれば、アクチュエ ータ5の電源12がオフの時に流体が貫通孔9から流入 して貫通者.10 側へ流れ、電源12がオンの時はアクチ ュエータ5が伸長してメサ部6により流出孔10を閉塞 するので、ノーマリオープン型のパルプを実現すること ができる。

[0006]

**【発明が解決しようとする課題】しかしながら,上記後 50 晶等からなる第2基板であり,この第2基板25にはガ** 

来のマイクロパルプは圧電アクチュエータの伸長距離が 極めて短いため腰整が難しく、また、アクチュエータを 接着により固定しているため長期安定性に問題がある。 さらに、パルプの集約、駆動回路、流量測定、検出器等 の他の機能の一体化をはかる場合、シリコン微細加工技 術によりパルプを同時に形成することは困難である。ま た、それぞれのパルプ1個に対し一つの駆動装置が必要 となるのでコスト高になるという問題がある。本発明は 上記従来技術の問題点を解決するためになされたもの る力を利用することにより、長期安定性にすぐれ、簡単 な構成で複数のパルプを同時に駆動することが可能なマ イクロパルプを提供することを目的とする。

[0007]

「趣晒を解決するための手段」上記舞蹈を解決する為に 本発明は、一方の面に凹部が形成され、該凹部と他方の 面でダイアフラムが形成された第1基板と、前記ダイア フラム上に固定された少なくとも一つのリング状のガス ケットと、前記第1基板のダイアフラムが形成された側 20 に所定の間隙を有して気密に配置され、前記ガスケット のほぼ中心に対向する位置に形成された第1貫通孔及び ガスケットの外間に対向する位置に形成された少なくと も一つの第2貫通穴を有する第2基板と、前配凹部を覆 って気密に配置された第3基板とを有し、前配凹部に加 熱 (若しくは冷却) により膨張 (若しくは収縮) する部 材を封入するとともに、咳部材の加熱(若しくは冷却) 手段を設けたことを特徴とするものである。

[0008]

【作用】通常状態では第1, 第2貫通孔は間隙を介して 連通し、流路が開(若しくは閉)の状態となっている。 第1基板の凹部に封入された部材を加熱(若しくは冷 却) 手段により加熱 (若しくは冷却) すると部材が膨張 (若しくは収縮) する。その結果ダイアフラムが撓んで ガスケットのほぼ中心に対向して配置された第1貫通孔 を閉塞 (若しくは解放) し流路は閉 (若しくは開) の状 餓となる。

[0009]

【実施例】以下図面を用いて本発明を説明する。図1は 本発明のマイクロバルブの一実施例を示す断面図であ であり、この第1基板の一方の面には異方性エッチング を用いて凹部21が形成されている。22は第1基板2 0の他方の側に形成された深さ数 um程度の開膛、23 は一辺が100μm~10mm程度、厚さ1~100μ m程度のダイアフラムである。24はダイアフラム上に 形成された厚さ数 um, 外径10 um~1mm程度の二 ッケルや命等からなるリング状のガスケットで、蒸着、 スパッタ等により形成されている。

【0010】25はパイレックスガラスやシリコン単結

3 スケット24に対向する位置に第1貫通孔26が形成さ れ、第1基板20に気密に固定されている。27は間隙 22に連通しガスケット24の外周に形成された第2貫 通孔, 30a, 30bは第1, 第2貫通孔26, 27に 接続された内径0.1~1mm程度の配管である。

【0011】32はパイレックスガラスやシリコン単結 晶等からなる第3基板であり、この第3基板32の一方 の面には金属薄膜抵抗体からなるヒータ33が形成さ れ、そのヒータ部分が第1基板の凹部内に位置するよう に気俗に固定されている。この凹部の密封に際しては例 10 うに第3基板32に第3貫通孔50を設け、他方の側に えばN2ガスを封入する。34は外部電極であり、ヒー タ33に電気絶縁層(図示せず)を介して気密に接続さ れている。

【0012】上記の構成において、通常状態では第1、 第2貫通孔26,27は間隙22を介して連通し、配管 30a. 30bを调る流体流路は肌の状態となってい る。そして、外部電板34に電源(図示せず)を接続し てヒータ33を加熱すると凹部に密封されたNaが膨張 する。その結果ダイアフラム23が点線で示すように撓 んでガスケット24のほぼ中心に対向して配置された第 20 【図面の簡単な説明】 1貫通孔26を閉塞し流路は閉の状態となる。

【0013】図2は他の実施例を示す断面図である。図 において図1と同一要素には同一符号を付して重複する 説明は省略するが、この実施例においては一点鎖線Aで 示す比較的大きめの凹部21aを形成し、この凹部を更 にエッチングして比較的に小さな3つの凹部21b,2 1 c. 2 1 dを形成し、それぞれのダイアフラム23 a, 23b, 23cにガスケット24a, 24b, 24 c を形成している。また、この実施例においては第3基 板20aの外側に密着してベルチェ素子40を設け、加 30 21 四部 熱(若しくは冷却)手段を構成している。41はペルチ ェ素子を加熱(若しくは冷却)するための電源である。 なお, この例においても凹部21a~24dにはNzガ ス等が封入されている。また、シリコン単結晶からなる 第1 基板20にPN接合からなる温度検出手段(関示せ ず)を設け、その温度検出手段からの信号に応じて電源 41のオンオフを行うことも可能である。

【0014】上記の構成によれば、一つの電源で3つの ダイアフラムを駆動することが可能であり一度に3つの 流路の開閉が可能である。また、ガスケット24a~2 40 34 外部電極 4 c と第2基板25 a の間隙22を適当に調整し、ペル チェ素子40と温度検出手段からの信号によりN2の温 度を削御すればノルマルクローズのパルプを実現するこ

とができ、更にパルブの開閉動作の信頼性と高速化を図 ることが可能である。

【0015】なお、本発明は上記実施例に限定するもの ではない。例えば封入部材としてはArガス, ハロゲン ガス、ネオンガス、キセノンガスなどでもよく、加熱に より気化して体積が膨張する様なものであればよい。更 に間隙22は第2基板側に設けてもよく、図2に示すダ イアフラムの数も3つに限ることなく任意であり、第2 貫通孔は2つ以上であってもよい。また、図3に示すよ もう一組の第1、第2基板20、25を設ければ更に多 数のパルプを開閉することが可能である。

#### [0016]

【発明の効果】以上実施例とともに具体的に説明したよ うに本発明によれば、ダイアフラムを駆動する手段とし て気体の膨張による力を利用することにより、長期安定 性にすぐれ。簡単な構成で複数のパルブを同時に駆動す ることが可能なマイクロパルプを実現することができ

【図1】本発明の一実施例を示すマイクロバルブの断面 構成図である。

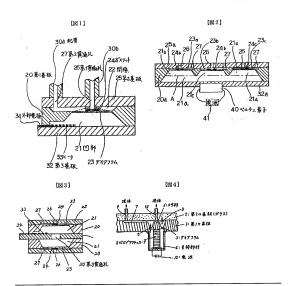
【図2】本発明の他の実施例を示すマイクロバルブの断 面構成図である。

【図3】 本発明の他の実施例を示すマイクロパルブの断 面構成図である。

【図4】従来のマイクロバルブの断面構成図である。

## 【符号の説明】 20 第1基板

- 22 間隙
- 23 ダイアフラム
- 24 ガスケット
- 25 第2基板
- 26 第1 質涌孔 27 第2貫通孔
- 30 配管
- 32 第3基板
- 33 ヒータ
- 40 ペルチェ素子
- 41 撤額



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## CLAIMS

## [Claim(s)]

[Claim 1] The 1st substrate with which the crevice was formed in one field and the diaphragm was formed in respect of this crevice and another side, The gasket of at least one shape of a ring fixed on said diaphragm. It has a predetermined gap in the side in which the diaphragm of said 1st substrate was formed. The 2nd substrate which has 2nd at least one through hole formed in the location which counters the periphery of the 1st breakthrough which has been arranged airtightly and formed in the location of said gasket which counters a core mostly, and a gasket, The micro bulb characterized by establishing the heating (or cooling) means of this member while enclosing the member which has the 3rd substrate which covered said crevice and has been arranged airtightly, and expands with heating (or cooling) to said crevice (or contraction).

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## DETAILED DESCRIPTION

## [Detailed Description of the Invention]

[0001]

[Industrial Application] This invention is used for the gas-passageway change of the micro gas chromatography formed for example, on the silicon substrate, and relates to a suitable micro bulb. 100021

[Description of the Prior Art] Conventionally, the thing of the structure shown in drawing 4 indicated by publication of unexamined utility model application Heisei 1-154460 as this kind of a micro bulb in a cross section is known. In drawing 4, 1 is the 1st substrate which consists of silicon, it is open for free passage to the crevice which the diaphragm which has the mesa section 6 is formed in the center section formed in this silicon substrate 1 of etching, and forms this diaphragm, and the slot 7 is formed. 2 is the 2nd substrate which consists of Pyrex glass, the breakthroughs 9 and 10 which serve as a gate of a fluid according to the location of the mesa section 6 and a slot 7 are formed, and the 1st and 2nd substrate is formed in piles of anode plate junction.

[0003] 4 is the supporter material of a cross-section U shape, covers the rear face of the mesa section 6 formed in the 1st substrate 1, and is being fixed by adhesives. 5 is an electrostrictive actuator (only henceforth an actuator), an end touches the pars basilaris ossis occipitalis of the supporter material 4, the other end touches the rear face of the mesa section 6 of the 1st substrate, and this actuator 5 is arranged. 12 is a power source for impressing an electrical potential difference to an actuator.

[0004] In addition, the thickness of the 1st substrate is about 6 micrometers, and the gap D of 0.3mm and the 2nd substrate is made into 4.2mm 2 and die length of about 9mm, and displaces about 8 micrometers of cross sections of an actuator with the electrical potential difference of 150V. [0005] Since according to the bulb of the above-mentioned configuration a fluid flows from a breakthrough 9 and flows to a breakthrough 10 side, when the power source 12 of an actuator 5 is OFF, an actuator 5 develops when a power source 12 is ON, and the runoff hole 10 is blockaded by the mesa section 6, the bulb of a NOMARI open type is realizable.

[0006]

[Problem(s) to be Solved by the Invention] However, since the above-mentioned conventional micro bulb has a very short expanding distance of an electrostrictive actuator, adjustment is difficult, and since the actuator is fixed by adhesion, when achieving the unification with the function of others further, such as concentration of a bulb, an actuation circuit, hydrometry, and a detector, which has a problem in long term stability, it is difficult [it] to form a bulb simultaneously with silicon ultra-fine processing technology. Moreover, since one driving gear is needed to each one bulb, there is a problem of becoming cost high. It was made in order that this invention might solve the trouble of the above-mentioned conventional technique, and as a means to drive a diaphragm, by using the force by expansion of a gas, it excels in long term stability and aims at offering the micro bulb which can drive simultaneously two or more bulbs with an easy configuration. [0007]

[Means for Solving the Problem] The 1st substrate with which, as for this invention, the crevice was

formed in one field, and the diaphragm was formed in respect of this crevice and another side in order to solve the above-mentioned technical problem. The gasket of at least one shape of a ring fixed on said diaphragm, It has a predetermined gap in the side in which the diaphragm of said 1st substrate was formed. The 2nd substrate which has 2nd at least one through hole formed in the location which counters the periphery of the 1st breakthrough which has been arranged airtightly and formed in the location of said gasket which counters a core mostly, and a gasket, It has the 3rd substrate which covered said crevice and has been arranged airtightly, and while enclosing the member which expands with heating (or cooling) to said crevice (or contraction), it is characterized by establishing the heating (or cooling) means of this member.

# [0008]

[Function] In the normal state, the 1st and 2nd breakthrough is open for free passage through a gap, and passage is in the open (or close) condition. If the member enclosed with the crevice of the 1st substrate is heated with a heating (or cooling) means (or cooling), a member will expand (or contraction). As a result, a diaphragm bends, the 1st breakthrough of a gasket which countered the core mostly and has been arranged is blockaded (or release), and passage will be in a close (or open) condition. 100091

[Example] This invention is explained using a drawing below. Drawing 1 is the sectional view showing one example of the micro bulb of this invention. In drawing, 20 is the 1st substrate which consists of a silicon single crystal, and the crevice 21 is formed in one field of this 1st substrate using anisotropic etching. One side of the gap with a depth of about several micrometers where 22 was formed in the another side side of the 1st substrate 20, and 23 is 100 micrometers - about 10mm and a diaphragm with a thickness of about 1-100 micrometers. 24 is the gasket of the shape of a ring which consists of nickel metallurgy with a micrometers [in thickness/several], and an outer diameter of 10 micrometers - about 1mm formed on the diaphragm, and is formed of vacuum evaporation, a spatter, etc.

[0010] 25 is the 2nd substrate which consists of Pyrex glass, a silicon single crystal, etc., and the 1st breakthrough 26 is formed in the location which counters a gasket 24, and it is being airtightly fixed to this 2nd substrate 25 by the 1st substrate 20. The 2nd breakthrough which 27 was open for free passage in the gap 22, and was formed in the periphery of a gasket 24, and 30a and 30b are piping with a bore of about 0.1-1 mm connected to the 1st and 2nd breakthrough 26 and 27.

- [0011] 32 is the 3rd substrate which consists of Pyrex glass, a silicon single crystal, etc., the heater 33 which consists of a metal thin film resistor is formed in one field of this 3rd substrate 32, and it is being airtightly fixed so that that heater part may be located in the crevice of the 1st substrate. N2 gas is enclosed on the occasion of seal of this crevice. 34 is an external electrode and is airtightly connected to the heater 33 through the electric insulation layer (not shown).
- [0012] In the above-mentioned configuration, by the normal state, the 1st and 2nd breakthrough 26 and 27 is open for free passage through a gap 22, and the fluid passage which passes along Piping 30a and 30b is in the open condition. And if a power source (not shown) is connected to the external electrode 34 and a heater 33 is heated, N2 sealed by the crevice will expand. As a result, it bends, as a diaphragm 23 shows by the dotted line, and the 1st breakthrough 26 of a gasket 24 which countered the core mostly and has been arranged is blockaded, and passage will be in a close condition.
- [0013] Drawing 2 is the sectional view showing other examples. Although the explanation which gives the same sign to the same element as drawing 1, and overlaps in drawing is omitted Form comparatively larger crevice 21a shown with an alternate long and short dash line A in this example, and this crevice is etched further. It is comparatively alike, three small crevices 21b, 21c, and 21d are formed, and Gaskets 24a, 24b, and 24c are formed in each diaphragm 23a, 23b, and 23c. Moreover, in this example, it sticks to the outside of 3rd substrate 20a, Peltier device 40 is formed, and the heating (or cooling) means is constituted. 41 is a power source for heating a Peltier device (or cooling). In addition, N2 gas etc. is enclosed with Crevices 21a-24d also in this example. Moreover, it is also possible to establish the temperature detection means (not shown) which becomes the 1st substrate 20 which consists of a silicon single crystal from a PN junction, and to turn a power source 41 on and off according to the signal from the temperature detection means.

[0014] According to the above-mentioned configuration, it is possible to drive three diaphragms with one power source, and closing motion of three passage is possible at once. Moreover, the gap 22 of Gaskets 24a-24c and 2nd substrate 25a is adjusted suitably, if the temperature of N2 is controlled by the signal from Peltier device 40 and a temperature detection means, the bulb of normal closing can be realized, and it is possible to attain the dependability of the switching action of a bulb and improvement in the speed further.

[0015] In addition, this invention is not limited to the above-mentioned example. The volume seems for example, for what is necessary to be for Ar gas, halogen gas, neon gas, xenon gas, etc. to be used as an enclosure member, and to evaporate with heating and just to expand. Furthermore, the gap 22 may be arbitrary, without also restricting the number of the diaphragms which may form in the 2nd substrate side and are shown in <u>drawing 2</u> to three, and the 2nd breakthrough may be two or more. Moreover, if the 3rd breakthrough 50 is formed in the 3rd substrate 32 as shown in <u>drawing 3</u>, and the 1st and 2nd substrate 20 and 25 of a lot is already formed in an another side side, it is possible to open and close many bulbs further.

[0016]

[Effect of the Invention] As a means to drive a diaphragm according to this invention as concretely explained with the example above, it excels in long term stability by using the force by expansion of a gas, and the micro bulb which can drive simultaneously two or more bulbs with an easy configuration can be realized.

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## TECHNICAL FIELD

[Industrial Application] This invention is used for the gas-passageway change of the micro gas chromatography formed for example, on the silicon substrate, and relates to a suitable micro bulb.

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## PRIOR ART

[Description of the Prior Art] Conventionally, the thing of the structure shown in drawing 4 indicated by publication of unexamined utility model application Heisei 1-154460 as this kind of a micro bulb in a cross section is known. In drawing 4, 1 is the 1st substrate which consists of silicon, it is open for free passage to the crevice which the diaphragm which has the mesa section 6 is formed in the center section formed in this silicon substrate 1 of etching, and forms this diaphragm, and the slot 7 is formed. 2 is the 2nd substrate which consists of Pyrex glass, the breakthroughs 9 and 10 which serve as a gate of a fluid according to the location of the mesa section 6 and a slot 7 are formed, and the 1st and 2nd substrate is formed in piles of anode plate junction.

100314 is the supporter material of a cross-section U shape, covers the rear face of the mesa section 6

formed in the 1st substrate 1, and is being fixed by adhesives. 5 is an electrostrictive actuator (only henceforth an actuator), an end touches the pars basilaris ossis occipitalis of the supporter material 4, the other end touches the rear face of the mesa section 6 of the 1st substrate, and this actuator 5 is arranged. 12 is a power source for impressing an electrical potential difference to an actuator. [0004] In addition, the thickness of the 1st substrate is about 6 micrometers, and the gap D of 0.3mm and the 2nd substrate is made into 4.2mm 2 and die length of about 9mm, and displaces about 8 micrometers of cross sections of an actuator with the electrical potential difference of 150V. [0005] Since according to the bulb of the above-mentioned configuration a fluid flows from a breakthrough 9 and flows to a breakthrough 10 side, when the power source 12 of an actuator 5 is OFF, an actuator 5 develops when a power source 12 is ON, and the runoff hole 10 is blockaded by the mesa

[Translation done.]

section 6, the bulb of a NOMARI open type is realizable.

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## EFFECT OF THE INVENTION

[Effect of the Invention] As a means to drive a diaphragm according to this invention as concretely explained with the example above, it excels in long term stability by using the force by expansion of a gas, and the micro bulb which can drive simultaneously two or more bulbs with an easy configuration can be realized.

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## TECHNICAL PROBLEM

[Problem(s) to be Solved by the Invention] However, since the above-mentioned conventional micro bulb has a very short expanding distance of an electrostrictive actuator, adjustment is difficult, and since the actuator is fixed by adhesion, when achieving the unification with the function of others further, such as concentration of a bulb, an actuation circuit, hydrometry, and a detector, which has a problem in long term stability, it is difficult [it] to form a bulb simultaneously with silicon ultra-fine processing technology. Moreover, since one driving gear is needed to each one bulb, there is a problem of becoming cost high. It was made in order that this invention might solve the trouble of the above-mentioned conventional technique, and as a means to drive a diaphragm, by using the force by expansion of a gas, it excels in long term stability and aims at offering the micro bulb which can drive simultaneously two or more bulbs with an easy configuration.

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## MEANS

[Means for Solving the Problem] The 1st substrate with which, as for this invention, the crevice was formed in one field, and the diaphragm was formed in respect of this crevice and another side in order to solve the above-mentioned technical problem. The gasket of at least one shape of a ring fixed on said diaphragm, It has a predetermined gap in the side in which the diaphragm of said 1st substrate was formed. The 2nd substrate which has 2nd at least one through hole formed in the location which counters the periphery of the 1st breakthrough which has been arranged airtightly and formed in the location of said gasket which counters a core mostly, and a gasket, It has the 3rd substrate which covered said crevice and has been arranged airtightly, and while enclosing the member which expands with heating (or cooling) to said crevice (or contraction), it is characterized by establishing the heating (or cooling) means of this member.

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## OPERATION

[Function] In the normal state, the 1st and 2nd breakthrough is open for free passage through a gap, and passage is in the open (or close) condition. If the member enclosed with the crevice of the 1st substrate is heated with a heating (or cooling) means (or cooling), a member will expand (or contraction). As a result, a diaphragm bends, the 1st breakthrough of a gasket which countered the core mostly and has been arranged is blockaded (or release), and passage will be in a close (or open) condition.

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#### EXAMPLE

[Example] This invention is explained using a drawing below. <u>Drawing 1</u> is the sectional view showing one example of the micro bulb of this invention. In drawing, 20 is the 1st substrate which consists of a silicon single crystal, and the crevice 21 is formed in one field of this 1st substrate using anisotropic etching. One side of the gap with a depth of about several micrometers where 22 was formed in the another side side of the 1st substrate 20, and 23 is 100 micrometers - about 10mm and a diaphragm with a thickness of about 1-100 micrometers. 24 is the gasket of the shape of a ring which consists of nickel metallurgy with a micrometers [in thickness / several], and an outer diameter of 10 micrometers - about 1mm formed on the diaphragm, and is formed of vacuum evaporationo, a spatter, etc.

[0010] 25 is the 2nd substrate which consists of Pyrex glass, a silicon single crystal, etc., and the 1st breakthrough 26 is formed in the location which counters a gasket 24, and it is being airtightly fixed to this 2nd substrate 25 by the 1st substrate 20. The 2nd breakthrough which 27 was open for free passage in the gap 22, and was formed in the periphery of a gasket 24, and 30a and 30b are piping with a bore of about 0.1-1 mm connected to the 1st and 2nd breakthrough 26 and 27.

[0011] 32 is the 3rd substrate which consists of Pyrex glass, a silicon single crystal, etc., the heater 33 which consists of a metal thin film resistor is formed in one field of this 3rd substrate 32, and it is being airtightly fixed so that that heater part may be located in the crevice of the 1st substrate. N2 gas is enclosed on the occasion of seal of this crevice. 34 is an external electrode and is airtightly connected to the heater 33 through the electric insulation layer (not shown).

[0012] In the above-mentioned configuration, by the normal state, the 1st and 2nd breakthrough 26 and 27 is open for free passage through a gap 22, and the fluid passage which passes along Piping 30a and 30b is in the open condition. And if a power source (not shown) is connected to the external electrode 34 and a heater 33 is heated, N2 sealed by the crevice will expand. As a result, it bends, as a diaphragm 23 shows by the dotted line, and the 1st breakthrough 26 of a gasket 24 which countered the core mostly and has been arranged is blockaded, and passage will be in a close condition.

[0013] Drawing 2 is the sectional view showing other examples. Although the explanation which gives the same sign to the same element as drawing 1, and overlaps in drawing is omitted Form comparatively larger crevice 21a shown with an alternate long and short dash line A in this example, and this crevice is etched further. It is comparatively alike, three small crevices 21b, 21c, and 21d are formed, and Gaskets 24a, 24b, and 24c are formed in each diaphragm 23a, 23b, and 23c. Moreover, in this example, it sticks to the outside of 3rd substrate 20a, Peltier device 40 is formed, and the heating (or cooling) means is constituted. 41 is a power source for heating a Peltier device (or cooling). In addition, N2 gas etc. is enclosed with Crevices 21a-24d also in this example. Moreover, it is also possible to establish the temperature detection means (not shown) which becomes the 1st substrate 20 which consists of a silicon single crystal from a PN junction, and to turn a power source 41 on and off according to the signal from the temperature detection means.

[0014] According to the above-mentioned configuration, it is possible to drive three diaphragms with one power source, and closing motion of three passage is possible at once. Moreover, the gap 22 of Gaskets 24a-24c and 2nd substrate 25a is adjusted suitably, if the temperature of N2 is controlled by the signal from Peltier device 40 and a temperature detection means, the bulb of normal closing can be realized, and it is possible to attain the dependability of the switching action of a bulb and improvement in the sneed further.

[0015] În addition, this invention is not limited to the above-mentioned example. The volume seems for example, for what is necessary to be for Ar gas, halogen gas, neon gas, xenon gas, etc. to be used as an enclosure member, and to evaporate with heating and just to expand. Furthermore, the gap 22 may be arbitrary, without also restricting the number of the diaphragms which may form in the 2nd substrate side and are shown in drawing 2 to three, and the 2nd breakthrough may be two or more. Moreover, if the 3rd breakthrough 50 is formed in the 3rd substrate 32 as shown in drawing 3, and the 1st and 2nd substrate 20 and 25 of a lot is already formed in an another side side, it is possible to open and close many bulbs further.

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## DESCRIPTION OF DRAWINGS

[Brief Description of the Drawings]

[Drawing 1] It is the cross-section block diagram of the micro bulb in which one example of this invention is shown.

[Drawing 2] It is the cross-section block diagram of the micro bulb in which other examples of this invention are shown.

[Drawing 3] It is the cross-section block diagram of the micro bulb in which other examples of this invention are shown.

[Drawing 4] It is the cross-section block diagram of the conventional micro bulb.

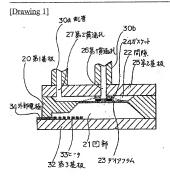
[Description of Notations]

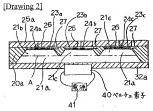
- 20 1st Substrate
- 21 Crevice
- 22 Gap
- 23 Diaphragm 24 Gasket
- 25 2nd Substrate
- 26 1st Breakthrough
- 27 2nd Breakthrough
- 30 Piping
- 32 3rd Substrate
- 33 Heater
- 34 External Electrode
- 40 Peltier Device
- 41 Power Source

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## DRAWINGS





[Drawing 3]

